Upgrading and Extending PON by Using In-Band WDM Overlay

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Abstract— This paper presents a new approach to upgrade and extend the reach of the current passive optical network (PON) by using wavelength division multiplexing (WDM) in the standardized optical grid of gigabit PON (In-band WDM PON overlay). The aim is to increase the number of optical distribution networks (ODNs) fed by a single fiber while preserving the users bandwidth. In this approach four downstream (DS) wavelength signals are transmitted from an optical line terminal (OLT) to four different ODNs using the standard DS PON spectrum ranging from 1480 to 1500 nm. The upstream (US) signals from the four different ODNs are also wavelength multiplexed within the standardized US PON spectrum ranging from 1270 to 1330 nm. Experimental proofs of concept are presented in a 20 km PON serving 32 ONTs and in a 58 km extended PON in order to demonstrate the feasibility of this proposal.

Index Terms— PON Overlay, PON Stacking, GPON, GEPON CWDM.

I. INTRODUCTION

Current passive optical networks (PON), such as gigabit passive optical network (GPON) and gigabit Ethernet passive optical network (GEPON), are recognized as market leaders in optical access deployments. The upgrade or the evolution of these networks has been proposed and analyzed in the literature [1]-[4].

The trivial PON evolution is to increase the transmission bit ratio to 10 Gb/s or to use dense wavelength division multiplexing (DWDM) [4]. However there are also some ITU-T studies to implement the concept of a coarse wavelength division multiplexing (CWDM) PON overlay or PON stacking, which are extensions of standard PON equipment based on several independent colored PON systems over a single optical distribution network (ODN) infrastructure and that enable a wavelength level unbundling [5]-[6].

Previous works proposed a CWDM PON overlay network to increase the number of ODNs powered by a single fiber [7]-[9]. In [7] a CWDM PON overlay was proposed to increase fourfold the downstream (DS) network capacity, while maintaining the ability to upstream (US) by 1.25 Gb/s. According to [7] the optical line terminal (OLT) is replaced keeping the optical network terminals (ONTs) unchanged. Three new OLT with wavelengths at 1430 nm, 1450 nm and 1470 nm, in addition
to the standardized PON channel of 1490 nm are used as downstream channels to the ONTs. The
same authors also analyze this topology in [8] applied for an extended reach PON. In [9] it is
presented the overlay of five gigabit signals operating between 1531nm to 1611nm over a working G-
PON.

Nowadays, these DS CWDM wavelengths are incompatible with the optical bandwidth of the
current ONT transceivers which work in the range from 1480 nm to 1500 nm (S band) according ITU-
T G.984.2 [10]. Therefore the ONT transceiver filter must be re-designed. However, ONT
transceivers are currently in mass production which makes difficult to apply this proposal in the
current PON architecture.

This paper presents a new approach to upgrade the current PON by using WDM in the standardized
PON optical grid. This approach is named In-band PON overlay. Four channels chosen in S band
(1482, 1486, 1492 and 1496 nm) are transmitted from the OLT to four different ODNs. The upstream
signals (1270, 1290, 1310 and 1330 nm) from the four different ODNs are also multiplexed within the
standardized OLT O band receiver spectrum. This procedure allows the network to be expanded
preserving the same standardized PON spectrum. In addition, the user bandwidths are kept unchanged
despite of the network upgrading. The network topology is described and an experimental proof of
concept is presented in order to demonstrate the feasibility of this proposal. In addition, we show the
feasibility to increase the reach of the proposed network by using SOA’s based extender. It is also
presented the experimental results of the extended network operation for four downstream channels
centered in 1490 nm and four upstream channels centered in 1300 nm, using downstream and
upstream transmission rate of 2.5 Gb/s in a 20 km PON serving 32 ONTs and in a 58 km extended
PON.

II. PON OVERLAY ARCHITECTURES

A. Previous CWDM PON overlay grids

The traditional PON overlay architecture is shown in Fig. 1. Several PONs use different CWDM
wavelengths for DS and US signals [11]. Therefore, the total capacity of the feeder fiber is increased,
making this architecture very attractive to extend the reach of feeder fiber. Since, the fiber plant cost
increases with the reach, sharing various ODNs in the same feeder is an effective way for network
operators to decrease the costs [11].
Fig. 1. Generic diagram for a CWDM PON overlay.

Fig. 2 shows the CWDM optical grid [12] available for PON overlay operation. The spectra reserved for GPON systems [10], XGPON [13] and Video Overlay [14] systems are also shown in this figure. These systems will coexist in the same current implanted optical network establishing probably the first standardized PON overlay.

Notice that in the CWDM PON overlay demonstration described in [6] the DS wavelengths are 1430 nm, 1450 nm, 1470 nm and 1490 nm (See Fig. 2). In the demonstration described in [8] the DS wavelengths are 1531 nm, 1551 nm, 1571 nm, 1591 and 1611 nm. None of these demonstrations includes grid for US channels.

Fig. 2. Available spectrum grid for a WDM PON overlay.

B. In-band WDM PON overlay architecture

The proposed in-band WDM PON overlay architecture is shown in Fig. 3. The basic concept is to increase the number of ODNs fed by just one single fiber. This PON architecture uses four S band wavelengths transmitted from an OLT to four different ODNs. The experiment makes use of selected commercial distributed feedback (DFB) lasers that operated in the standardized PON DS spectrum band (1480 nm to 1500 nm). The downstream wavelengths are 1482, 1487, 1492 and 1497 nm (Fig.2). The 5 nm spacing between the wavelengths is allowed to match with the grid of selected commercial S band WDM multiplexers (mux) used in Raman amplifiers.
In the OLT the four S band channels are multiplexed in the feeder fiber by means of one S band mux and one 1x2 1490 nm add/drop CWDM filter. The same add/drop filter connects the upstream channels to one 1x4 O band CWDM demultiplexer (demux) that is followed by the optical OLT receivers.

In the far end of the feeder fiber, the downstream channels and the upstream channels are again routed by other 1x2 1490 nm add/drop CWDM filter. The downstream channels are inserted into four ODNs by means of one S band demux. Notice that each ODN contains one 2xN splitter.

All ONTs transmitters, belonging to a given ODN, send the upstream signals using a specific CWDM channel. The wavelengths for the four OLTs are in the range from 1270 nm to 1330 nm (Fig.2). These wavelengths have been chosen by the following reasons: they are within the standardized OLT receiver spectrum; they are CWDM channels standardized by ITU-T [12]; they have already been used in deployed PONs [5], and also they allow PON extension by using semiconductor optical amplifiers (SOAs) with spectrum gain matched to these wavelengths [15].

The upstream channels, after passing through the splitters, are multiplexed by means of one 1x4 O band CWDM mux and they are connected in the feeder fiber by the 1x2 1490 nm add/drop CWDM filter. The 1x4 O band CWDM mux may be replaced by one 1x4 splitter if its insertion loss can be absorbed by the link power budget.

In the OLT, other 1x2 1490 nm add/drop CWDM filter directs the upstream signals to a 1x4 O band CWDM demux and, finally, to the optical receivers.

A PON extender based on the use of SOAs has also been utilized before the ODNs. This application is better described in the next section.
III. PROOFS OF CONCEPT

A. Network Upgrading

The in-band WDM PON overlay architecture shown in Fig. 3 was firstly implemented without a PON extender. The feeder fiber length was 20 km composed by a standard single mode fiber. The OLT and the ONT channels performance were evaluated in terms of bit error rate (BER), using transmission bit rate of 2.5 Gb/s, and a pseudo-random binary sequence (PRBS) with length equal to $2^{23}-1$. Fig. 4 shows the OLT and OLT prototype diagrams used only to demonstrate our proposal. In the OLT, four S band DFB lasers operating in continuous wave (CW) power inject their signals in one Mach-Zender (MZ) LiNbO3 modulator by means of the S band mux. Polarization controllers are used to adjust the right polarization of the signals in the modulator input. The electrical signal of a pattern generator is amplified before injected in the MZ modulator.

![Diagram of OLT and OLT prototype](image)

Each ONT uses a commercial CWDM small form pluggable (SFP) transceivers and one 1x2 1490 nm add/drop CWDM filter to connect the downstream channel in the receiver and the upstream channel in the 2x32 splitter arm. The ONT and OLT receivers use APD (Avalanche Photo Diode) detectors with -31 dBm average sensitivity (ONT) and -33.5 dBm average sensitivity (OLT). The average optical power transmitted by each laser in S band is 1.3 dBm and 0 dBm for O band CWDM.

Fig. 5 shows the total insertion loss/insulation of (a) S band demultiplexer, (b) 1490 add/drop CWDM and (c) O band demultiplexer. The maximum insertion losses for multi/demultiplexers are: S band WDM mux/demux = 1.6 dB, O band WDM mux/demux = 1.8 dB, 1490 nm add/drop CWDM filter = 0.7 dB and the 2x32 Splitter = 15.8 dB. The fiber attenuation at O band ranges from 0.39 dB/km dB at 1270 nm to 0.31 dB/km at 1330 nm. At S band, the average fiber attenuation is 0.22 dB/km.
Fig. 5. Mux loss/insulation for (a) S band, (b) 1490 add/drop CWDM and (c) O band.

Fig. 6(a) shows the BER performance evaluation for S band channels and Fig. 6(b) shows it to O band channels measured, respectively, in the ONT and in OLT with and without fiber (BTB). The power penalty is null at \( \text{BER} = 1 \times 10^{-12} \) for downstream channels and it is around 2 dB for upstream channels. The power penalty for upstream channels is entirely absorbed by the system optical budged. The margin for the downstream and upstream channels is 2 dB at \( \text{BER} = 1 \times 10^{-12} \). Fig. 7 shows the spectrum in OLT of transmitted downstream and received upstream channels.
Fig. 6. The BER performance evaluation for (a) S band downstream channels measured in ONT and (b) O band upstream channels measured in OLT.

Fig. 7. Optical spectrum of downstream and upstream signals in OLT for a 20 km reach PON.
B. Network Upgrading and Extending

In order to verify the reach increase of in-band WDM PON overlay architecture, a PON extender based in SOAs is used. The bi-directional SOAs circuit is presented in Fig. 8. It is utilized a 1310/1490 nm fuser coupler to connect the input and output of two commercial SOAs, one for 1310 nm spectral band and other for 1490 nm spectral band. Fig. 3 shows the extender position in the fiber link, i.e., after 50 km from the OLT. Following the PON extender it is deployed 8 km fiber. These two fiber links have same attenuation as for the 20 km link previously described.

![Fig. 8. Details of the bidirectional PON extender.](image)

Typical characteristics of the SOAs are: loss signal gain greater than 15 dB in 1490 nm and in 1310 nm, operation current equal to 200 mA, and polarization sensitivity better than 1.5 dB. An optical attenuator is used in the input of the 1490 nm SOA to avoid BER degradation caused by cross gain modulation in nonlinear regime. Fig. 9 shows the spectrum of the PON extender outputs according to its position presented in Fig. 1. Notice that the gain bandwidth is 15 nm in S band and it is 60 nm in O band.

In the position where the extender is utilized the average input power per channel for S band channels is approximately -13.5 dBm (-23.5 dBm after the attenuator) and the gains are 13.5 dB (1482 nm), 13.8 dB (1487 nm), 13.1 dB (1492 nm) and 12.8 dB (1497 nm). The gains for O band channels are (average input power per channel ≈ -24 dBm): 11.9 dB (1270 nm), 17.4 dB (1290 nm), 16.8 dB (1310 nm) and 14.1 dB (1330 nm).

![Fig. 9. Optical spectrum in the extender outputs for downstream and upstream channels.](image)
Fig. 10(a) shows the BER performance evaluation for S band and Fig. 10(b) shows the BER performance evaluation for O band channels measured in the ONT and in OLT, respectively, compared to BTB measurements. The power penalty is around 7 dB at BER = 1x10^{-12} for S band channels and it is around 4 dB for O band. These penalties are attributed to the signal-to-ASE (Amplified Spontaneous Emission) beat noise process in the optical receivers.

Further experiments were conducted in order to test the ONT receiver performance due to the possible thermal wavelength variation of S band lasers. Since the S band multiplexer/demultiplexer transmission band is not flat (see Fig. 5(a)), the spectral variation of S band lasers can degrade the BER in the ONTs. Figure 11 shows the BER and received power performance of one S band channel (1492 nm) measured in an ONT receiver when the wavelength of the laser is thermally changed by +/- 2.5 nm. It is observed that the BER performance is not changed for +/-0.75 nm because the optical received power does not change in this range. This specific measurement point was chosen to demonstrate the problems concerned with the channel bandwidth.

Fig. 10. The extended PON BER performance evaluation for (a) S band downstream channels measured in ONT and (b) O band upstream channels measured in OLT.

According this evaluation the maximum temperature operation for the S band lasers in this proposed system with no BER degradation is 35 ºC, considering that a DFB lasers changes their
wavelengths by 0.075 nm/ºC. The S band mux and demux using dielectric filters technology could extend the operational temperature range since they have flat bandwidth, however they are not available in S band currently with 5 nm wavelength spacing.

Fig.11. BER and received power performance of one S band channel (1492 nm) measured in ONT receiver when the laser wavelength is changed by +/- 2.5 nm.

IV. CONCLUSION

This paper has presented a new proposal to upgrade and to extend the currently PON by using WDM in the standard GPON or EPON optical grid. The aim is to increase the number of optical distribution networks powered by a single fiber while preserving the users’ bandwidth. Four wavelengths channels are transmitted from the OLT to four different ODNs using the standardized ONT receiver ranging from 1480 to 1500 nm. The upstream channels from the four different ODNs are also wavelength multiplexed using the standardized OLT receiver band spectrum ranging from 1270 to 1330 nm. The network topology has been described and an experimental proof of concept has been presented. The good bit-error-rate performance presented by the proposal has shown its feasibility.

REFERENCES


